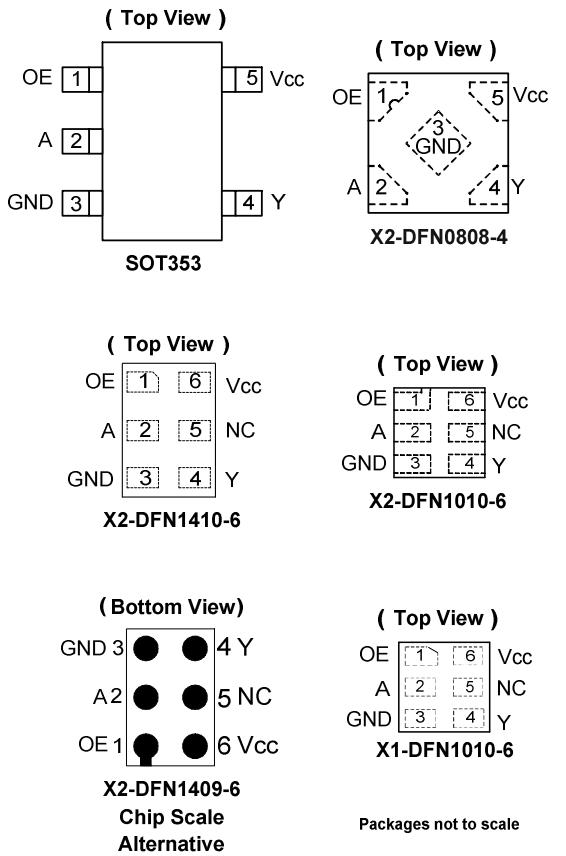


Description

The Advanced, Ultra Low Power (AUP) CMOS logic family is designed for low power and extended battery life in portable applications.

The 74AUP1G126 is a single, non-inverting, buffer/bus driver, designed for operation over a power supply range of 0.8V to 3.6V. The device has a three-state output that enters a high-impedance state when a LOW-level is applied to the Output Enable (OE) pin. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing damaging current backflow when the device is powered down.

Pin Assignments



Features

- Advanced Ultra Low Power (AUP) CMOS
- Supply Voltage Range from 0.8V to 3.6V
- $\pm 4\text{mA}$ Output Drive at 3.0V
- Low Static Power Consumption
 $I_{CC} < 0.9\mu\text{A}$
- Low Dynamic Power Consumption
 $C_{PD} = 6.3\text{pF}$ (Typical at 3.6V)
- Schmitt Trigger Action at all inputs makes the circuit tolerant for slower input rise and fall time. The hysteresis is typically 250mV at $V_{CC} = 3.0\text{V}$.
- I_{OFF} Supports Partial-Power-Down Mode Operation
- ESD Protection Exceeds JESD 22
2000-V Human Body Model (A114)
Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Leadless Packages named per JESD30E
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)**

Applications

- Suited for Battery and Low Power Needs
- Wide array of products such as:
 - Tablets, E-readers
 - Cell Phones, Personal Navigation / GPS
 - MP3 Players, Cameras, Video Recorders
 - PCs, Ultrabooks, Notebooks, Netbooks,
 - Computer Peripherals, Hard Drives, CD/DVD ROMs
 - TVs, DVDs, DVRs, Set-Top Boxes

Notes:

- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Ordering Information

| Logic Device | Function | Package | Packing |
|--------------------|---------------------------------------|---------------------|---------------------|
| 74 : Logic Prefix | | SE : SOT353 | -7 : 7" Tape & Reel |
| AUP : 0.8 to 3.6 V | | FS3 : X2-DFN0808-4 | |
| Logic Family | | FW5 : X1-DFN1010-6 | |
| 1G : One Gate | 126: 3-State Buffer OE active HIGH | FW4 : X2-DFN1010-6 | |
| | | FX4 : X2- DFN1409-6 | |
| | | FZ4 : X2- DFN1410-6 | |

| Device | Package Code | Package (Notes 4 & 5) | Package Size | 7" Tape and Reel | |
|-----------------|--------------|--|--|-------------------|--------------------|
| | | | | Quantity | Part Number Suffix |
| 74AUP1G126SE-7 | SE | SOT353 | 2.0mm x 2.0mm x 1.1mm 0.65 mm lead pitch | 3,000/Tape & Reel | -7 |
| 74AUP1G126FS3-7 | FS3 | X2-DFN0808-4 | 0.8mm x 0.8mm x 0.35mm 0.5 mm pad pitch (diamond) | 5,000/Tape & Reel | -7 |
| 74AUP1G126FW5-7 | FW5 | X1-DFN1010-6 | 1.0mm x 1.0mm x 0.5mm 0.35 mm pad pitch | 5,000/Tape & Reel | -7 |
| 74AUP1G126FW4-7 | FW4 | X2-DFN1010-6 | 1.0mm x 1.0mm x 0.4mm 0.35 mm pad pitch | 5,000/Tape & Reel | -7 |
| 74AUP1G126FX4-7 | FX4 | X2-DFN1409-6 Chip Scale Alternative | 1.4mm x 0.9mm x 0.4mm 0.5 mm pad pitch | 5,000/Tape & Reel | -7 |
| 74AUP1G126FZ4-7 | FZ4 | X2-DFN1410-6 | 1.4mm x 1.0mm x 0.4mm 0.5 mm pad pitch | 5,000/Tape & Reel | -7 |

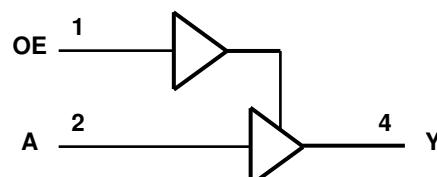
Notes: 4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

5. The taping orientation is located on our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Pin Descriptions

| Pin Name | Function |
|----------|----------------|
| OE | Output Enable |
| A | Data Input |
| GND | Ground |
| Y | Data Output |
| Vcc | Supply Voltage |

Logic Diagram



Function Table

| Inputs | | Output |
|--------|---|--------|
| OE | A | Y |
| H | H | H |
| H | L | L |
| L | X | Z |

Absolute Maximum Ratings (Notes 6 & 7) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Symbol | Description | Rating | Unit |
|-----------|---|------------------------|------|
| ESD HBM | Human Body Model ESD Protection | 2 | kV |
| ESD CDM | Charged Device Model ESD Protection | 1 | kV |
| V_{CC} | Supply Voltage Range | -0.5 to +4.6 | V |
| V_I | Input Voltage Range | -0.5 to +4.6 | V |
| V_O | Voltage Applied to Output in High or Low State | -0.5 to $V_{CC} + 0.5$ | V |
| I_{IK} | Input Clamp Current $V_I < 0$ | 50 | mA |
| I_{OK} | Output Clamp Current ($V_O < 0$) | 50 | mA |
| I_O | Continuous Output Current ($V_O = 0$ to V_{CC}) | ± 20 | mA |
| I_{CC} | Continuous Current Through V_{CC} | 50 | mA |
| I_{GND} | Continuous Current Through GND | -50 | mA |
| T_J | Operating Junction Temperature | -40 to +150 | °C |
| T_{STG} | Storage Temperature | -65 to +150 | °C |

- Notes:
- 6. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
 - 7. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

Recommended Operating Conditions (Note 8) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Symbol | Parameter | Min | Max | Unit | |
|---------------------|------------------------------------|---|----------|------|------|
| V_{CC} | Operating Voltage | 0.8 | 3.6 | V | |
| V_I | Input Voltage | 0 | 3.6 | V | |
| V_O | Output Voltage | 0 | V_{CC} | V | |
| I_{OH} | High-Level Output Current | $V_{CC} = 0.8\text{V}$ | — | -20 | μA |
| | | $V_{CC} = 1.1\text{V}$ | — | -1.1 | mA |
| | | $V_{CC} = 1.4\text{V}$ | — | -1.7 | |
| | | $V_{CC} = 1.65\text{V}$ | — | -1.9 | |
| | | $V_{CC} = 2.3\text{V}$ | — | -3.1 | |
| | | $V_{CC} = 3.0\text{V}$ | — | -4 | |
| I_{OL} | Low-Level Output Current | $V_{CC} = 0.8\text{V}$ | — | 20 | μA |
| | | $V_{CC} = 1.1\text{V}$ | — | 1.1 | mA |
| | | $V_{CC} = 1.4\text{V}$ | — | 1.7 | |
| | | $V_{CC} = 1.65\text{V}$ | — | 1.9 | |
| | | $V_{CC} = 2.3\text{V}$ | — | 3.1 | |
| | | $V_{CC} = 3.0\text{V}$ | — | 4 | |
| $\Delta t/\Delta V$ | Input Transition Rise or Fall Rate | $V_{CC} = 0.8\text{V}$ to 3.6V | — | 200 | ns/V |
| T_A | Operating Free-Air Temperature | -40 | +125 | °C | |

- Note:
- 8. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Symbol | Parameter | Test Conditions | V_{CC} | $T_A = +25^\circ\text{C}$ | | $T_A = -40^\circ\text{C} \text{ to } +85^\circ\text{C}$ | | Unit |
|------------------|----------------------------------|--|----------------|---------------------------|----------------------|---|----------------------|---------------|
| | | | | Min | Max | Min | Max | |
| V_{IH} | High-Level Input Voltage | — | 0.8V to 1.65V | 0.80 $\times V_{CC}$ | — | 0.80 $\times V_{CC}$ | — | V |
| | | — | 1.65V to 1.95V | 0.65 $\times V_{CC}$ | — | 0.65 $\times V_{CC}$ | — | |
| | | — | 2.3V to 2.7V | 1.6 | — | 1.6 | — | |
| | | — | 3.0V to 3.6V | 2.0 | — | 2.0 | — | |
| V_{IL} | Low-Level Input Voltage | — | 0.8V to 1.65V | — | 0.30 $\times V_{CC}$ | — | 0.30 $\times V_{CC}$ | V |
| | | — | 1.65V to 1.95V | — | 0.35 $\times V_{CC}$ | — | 0.35 $\times V_{CC}$ | |
| | | — | 2.3V to 2.7V | — | 0.7 | — | 0.7 | |
| | | — | 3.0V to 3.6V | — | 0.9 | — | 0.9 | |
| V_{OH} | High-Level Output Voltage | $I_{OH} = -20\mu\text{A}$ | 0.8V to 3.6V | $V_{CC} - 0.1$ | — | $V_{CC} - 0.1$ | — | V |
| | | $I_{OH} = -1.1\text{mA}$ | 1.1V | 0.75 $\times V_{CC}$ | — | 0.7 $\times V_{CC}$ | — | |
| | | $I_{OH} = -1.7\text{mA}$ | 1.4V | 1.11 | — | 1.03 | — | |
| | | $I_{OH} = -1.9\text{mA}$ | 1.65V | 1.32 | — | 1.3 | — | |
| | | $I_{OH} = -2.3\text{mA}$ | 2.3V | 2.05 | — | 1.97 | — | |
| | | $I_{OH} = -3.1\text{mA}$ | | 1.9 | — | 1.85 | — | |
| | | $I_{OH} = -2.7\text{mA}$ | 3V | 2.72 | — | 2.67 | — | |
| | | $I_{OH} = -4\text{mA}$ | | 2.6 | — | 2.55 | — | |
| V_{OL} | Low-Level Output Voltage | $I_{OL} = 20\mu\text{A}$ | 0.8V to 3.6V | — | 0.1 | — | 0.1 | V |
| | | $I_{OL} = 1.1\text{mA}$ | 1.1V | — | 0.3 $\times V_{CC}$ | — | 0.3 $\times V_{CC}$ | |
| | | $I_{OL} = 1.7\text{mA}$ | 1.4V | — | 0.31 | — | 0.37 | |
| | | $I_{OL} = 1.9\text{mA}$ | 1.65V | — | 0.31 | — | 0.35 | |
| | | $I_{OL} = 2.3\text{mA}$ | 2.3V | — | 0.31 | — | 0.33 | |
| | | $I_{OL} = 3.1\text{mA}$ | | — | 0.44 | — | 0.45 | |
| | | $I_{OL} = 2.7\text{mA}$ | 3V | — | 0.31 | — | 0.33 | |
| | | $I_{OL} = 4\text{mA}$ | | — | 0.44 | — | 0.45 | |
| I_I | Input Current | $V_I = \text{GND}$ to 3.6V | 0 to 3.6V | — | ± 0.1 | — | ± 0.5 | μA |
| I_{OFF} | Power Down Leakage Current | V_I or $V_O = 0\text{V}$ to 3.6V | 0 | — | ± 0.2 | — | ± 0.5 | μA |
| I_{OZ} | Z State Leakage Current | $V_O = 3.6\text{V}$ $V_I = 3.6\text{V}$ | 3.6V | — | ± 0.2 | — | ± 0.5 | μA |
| ΔI_{OFF} | Delta Power Down Leakage Current | V_I or $V_O = 0\text{V}$ to 3.6V | 0 to 0.2V | — | 0.2 | — | 0.6 | μA |
| I_{CC} | Supply Current | $V_I = \text{GND}$ or V_{CC} , $I_O = 0$ | 0.8V to 3.6V | — | 0.5 | — | 0.9 | μA |
| ΔI_{CC} | Additional Supply Current | Data Input at $V_{CC} - 0.6\text{V}$ $OE = \text{GND}$ $I_O = 0\text{A}$ | 3.3V | — | 40 | — | 50 | μA |
| | | OE Input at $V_{CC} - 0.6\text{V}$ Data Input = GND or V_{CC} , $I_O = 0\text{A}$ | 3.3V | — | 110 | — | 120 | μA |
| | | OE Input at GND Data Input = GND to 3.6V, $I_O = 0\text{A}$ | 0.8V to 3.6V | — | 1 | — | 1 | μA |

Electrical Characteristics (continued) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Symbol | Parameter | Test Conditions | V_{CC} | $T_A = -40^\circ\text{C} \text{ to } +125^\circ\text{C}$ | | Unit |
|------------------|----------------------------------|--|----------------|--|----------------------|---------------|
| | | | | Min | Max | |
| V_{IH} | High-Level Input Voltage | — | 0.8V to 1.65V | $0.80 \times V_{CC}$ | — | V |
| | | — | 1.65V to 1.95V | $0.70 \times V_{CC}$ | — | |
| | | — | 2.3V to 2.7V | 1.6 | — | |
| | | — | 3.0V to 3.6V | 2.0 | — | |
| V_{IL} | Low-Level Input Voltage | — | 0.8V to 1.65V | — | $0.25 \times V_{CC}$ | V |
| | | — | 1.65V to 1.95V | — | $0.35 \times V_{CC}$ | |
| | | — | 2.3V to 2.7V | — | 0.7 | |
| | | — | 3.0V to 3.6V | — | 0.9 | |
| V_{OH} | High-Level Output Voltage | $I_{OH} = -20\mu\text{A}$ | 0.8V to 3.6V | $V_{CC} - 0.11$ | — | V |
| | | $I_{OH} = -1.1\text{mA}$ | 1.1V | $0.6 \times V_{CC}$ | — | |
| | | $I_{OH} = -1.7\text{mA}$ | 1.4V | 0.93 | — | |
| | | $I_{OH} = -1.9\text{mA}$ | 1.65V | 1.17 | — | |
| | | $I_{OH} = -2.3\text{mA}$ | 2.3V | 1.77 | — | |
| | | $I_{OH} = -3.1\text{mA}$ | | 1.67 | — | |
| | | $I_{OH} = -2.7\text{mA}$ | 3V | 2.40 | — | |
| | | $I_{OH} = -4\text{mA}$ | | 2.30 | — | |
| V_{OL} | Low-Level Output Voltage | $I_{OL} = 20\mu\text{A}$ | 0.8V to 3.6V | — | 0.11 | V |
| | | $I_{OL} = 1.1\text{mA}$ | 1.1V | — | $0.3 \times V_{CC}$ | |
| | | $I_{OL} = 1.7\text{mA}$ | 1.4V | — | 0.41 | |
| | | $I_{OL} = 1.9\text{mA}$ | 1.65V | — | 0.39 | |
| | | $I_{OL} = 2.3\text{mA}$ | 2.3V | — | 0.36 | |
| | | $I_{OL} = 3.1\text{mA}$ | | — | 0.50 | |
| | | $I_{OL} = 2.7\text{mA}$ | 3V | — | 0.36 | |
| | | $I_{OL} = 4\text{mA}$ | | — | 0.50 | |
| I_I | Input Current | $V_I = \text{GND}$ to 3.6V | 0 to 3.6V | — | ± 0.75 | μA |
| I_{OFF} | Power Down Leakage Current | V_I or $V_O = 0\text{V}$ to 3.6V | 0 | — | ± 3.5 | μA |
| I_{OZ} | Z State Leakage Current | $V_O = 3.6\text{V}$ $V_I = 3.6\text{V}$ | 3.6V | — | ± 1.5 | μA |
| ΔI_{OFF} | Delta Power Down Leakage Current | V_I or $V_O = 0\text{V}$ to 3.6V | 0V to 0.2V | — | ± 2.5 | μA |
| I_{CC} | Supply Current | $V_I = \text{GND}$ or V_{CC} , $I_O = 0$ | 0.8V to 3.6V | — | 3.0 | μA |
| ΔI_{CC} | Additional Supply Current | Data Input at $V_{CC} - 0.6\text{V}$ $OE = \text{GND}$ $I_O = 0\text{A}$ | 3.3V | — | 75 | μA |
| | | OE input at $V_{CC} - 0.6\text{V}$ Data Input = GND or V_{CC} , $I_O = 0\text{A}$ | 3.3V | — | 180 | μA |
| | | OE Input at GND Data Input = GND to 3.6V, $I_O = 0\text{A}$ | 0.8V to 3.6V | — | 1 | μA |

Switching Characteristics

$C_L = 5\text{pF}$, See Figure 1

| Parameter | From Input | To Output | V_{CC} | $T_A = +25^\circ\text{C}$ | | | $T_A = -40^\circ\text{C} \text{ to } +85^\circ\text{C}$ | | $T_A = -40^\circ\text{C} \text{ to } +125^\circ\text{C}$ | | Unit |
|-----------|------------|-----------|------------------|---------------------------|------|------|---|------|--|------|------|
| | | | | Min | Typ | Max | Min | Max | Min | Max | |
| t_{pd} | A | Y | 0.8V | — | 20.6 | — | — | — | — | — | ns |
| | | | $1.2V \pm 0.1V$ | 2.5 | 5.5 | 10.5 | 2.5 | 11.7 | 2.5 | 12.9 | |
| | | | $1.5V \pm 0.1V$ | 2.0 | 3.9 | 6.1 | 2.0 | 7.3 | 2.0 | 8.1 | |
| | | | $1.8V \pm 0.15V$ | 1.9 | 3.2 | 4.8 | 1.7 | 6.1 | 1.7 | 6.7 | |
| | | | $2.5V \pm 0.2V$ | 1.6 | 2.6 | 3.6 | 1.4 | 4.3 | 1.4 | 4.9 | |
| | | | $3.3V \pm 0.3V$ | 1.4 | 2.4 | 3.1 | 1.2 | 3.9 | 1.2 | 4.4 | |
| t_{en} | OE | Y | 0.8V | — | 71.6 | — | — | — | — | — | ns |
| | | | $1.2V \pm 0.1V$ | 2.8 | 6.2 | 12.4 | 2.6 | 13.6 | 2.6 | 13.6 | |
| | | | $1.5V \pm 0.1V$ | 2.1 | 4.2 | 6.9 | 2.1 | 7.4 | 2.1 | 7.7 | |
| | | | $1.8V \pm 0.15V$ | 1.7 | 3.3 | 5.3 | 1.7 | 5.9 | 1.7 | 6.2 | |
| | | | $2.5V \pm 0.2V$ | 1.4 | 2.4 | 3.6 | 1.4 | 3.8 | 1.4 | 4.1 | |
| | | | $3.3V \pm 0.3V$ | 1.3 | 2.0 | 2.9 | 1.2 | 3.2 | 1.2 | 3.4 | |
| t_{dis} | OE | Y | 0.8V | — | 10.3 | — | — | — | — | — | ns |
| | | | $1.2V \pm 0.1V$ | 2.6 | 4.2 | 8.2 | 2.6 | 8.9 | 2.6 | 8.9 | |
| | | | $1.5V \pm 0.1V$ | 2.1 | 3.2 | 6.7 | 2.1 | 7.0 | 2.1 | 7.0 | |
| | | | $1.8V \pm 0.15V$ | 1.7 | 3.1 | 6.2 | 1.7 | 6.5 | 1.7 | 6.5 | |
| | | | $2.5V \pm 0.2V$ | 1.3 | 2.9 | 5.7 | 1.3 | 5.8 | 1.3 | 5.8 | |
| | | | $3.3V \pm 0.3V$ | 1.2 | 2.8 | 4.5 | 1.2 | 4.7 | 1.2 | 4.7 | |

$C_L = 10\text{pF}$, See Figure 1

| Parameter | From Input | To Output | V_{CC} | $T_A = +25^\circ\text{C}$ | | | $T_A = -40^\circ\text{C} \text{ to } +85^\circ\text{C}$ | | $T_A = -40^\circ\text{C} \text{ to } +125^\circ\text{C}$ | | Unit |
|-----------|------------|-----------|------------------|---------------------------|------|------|---|------|--|------|------|
| | | | | Min | Typ | Max | Min | Max | Min | Max | |
| t_{pd} | A | Y | 0.8V | — | 24.0 | — | — | — | — | — | ns |
| | | | $1.2V \pm 0.1V$ | 2.6 | 6.4 | 12.3 | 2.6 | 13.8 | 2.6 | 15.2 | |
| | | | $1.5V \pm 0.1V$ | 2.1 | 4.5 | 7.3 | 2.1 | 8.5 | 2.1 | 9.4 | |
| | | | $1.8V \pm 0.15V$ | 1.9 | 3.8 | 5.5 | 1.9 | 6.8 | 1.9 | 7.6 | |
| | | | $2.5V \pm 0.2V$ | 1.7 | 3.2 | 4.2 | 1.7 | 5.3 | 1.7 | 5.9 | |
| | | | $3.3V \pm 0.3V$ | 1.6 | 3.0 | 3.8 | 1.6 | 4.6 | 1.6 | 5.2 | |
| t_{en} | OE | Y | 0.8V | — | 75.3 | — | — | — | — | — | ns |
| | | | $1.2V \pm 0.1V$ | 3.0 | 7.1 | 14.1 | 3.0 | 15.4 | 3.0 | 15.4 | |
| | | | $1.5V \pm 0.1V$ | 2.1 | 4.8 | 8.0 | 2.1 | 8.3 | 2.1 | 8.6 | |
| | | | $1.8V \pm 0.15V$ | 1.7 | 3.9 | 5.9 | 1.7 | 6.5 | 1.7 | 6.8 | |
| | | | $2.5V \pm 0.2V$ | 1.4 | 2.9 | 4.2 | 1.4 | 4.5 | 1.4 | 4.8 | |
| | | | $3.3V \pm 0.3V$ | 1.3 | 2.6 | 3.6 | 1.3 | 3.8 | 1.3 | 4.0 | |
| t_{dis} | OE | Y | 0.8V | — | 12.2 | — | — | — | — | — | ns |
| | | | $1.2V \pm 0.1V$ | 3.3 | 7.9 | 10.1 | 3.3 | 11.1 | 3.3 | 11.1 | |
| | | | $1.5V \pm 0.1V$ | 2.1 | 7.0 | 9.3 | 2.1 | 10.1 | 2.1 | 10.1 | |
| | | | $1.8V \pm 0.15V$ | 1.7 | 6.3 | 8.7 | 1.7 | 9.1 | 1.7 | 9.1 | |
| | | | $2.5V \pm 0.2V$ | 1.4 | 4.9 | 7.6 | 1.4 | 7.8 | 1.4 | 7.8 | |
| | | | $3.3V \pm 0.3V$ | 1.3 | 4.1 | 5.7 | 1.3 | 5.8 | 1.3 | 5.8 | |

Switching Characteristics (continued)
 $C_L = 15\text{pF}$, See Figure 1

| Parameter | From Input | To Output | V_{CC} | $T_A = +25^\circ\text{C}$ | | | $T_A = -40^\circ\text{C} \text{ to } +85^\circ\text{C}$ | | $T_A = -40^\circ\text{C} \text{ to } +125^\circ\text{C}$ | | Unit |
|-----------|------------|-----------|------------------|---------------------------|------|------|---|------|--|------|------|
| | | | | Min | Typ | Max | Min | Max | Min | Max | |
| t_{pd} | A | Y | 0.8V | — | 27.4 | — | — | — | — | — | ns |
| | | | $1.2V \pm 0.1V$ | 3.6 | 7.2 | 14.1 | 3.3 | 15.8 | 3.3 | 17.5 | |
| | | | $1.5V \pm 0.1V$ | 3.0 | 5.1 | 8.1 | 2.5 | 9.8 | 2.5 | 10.9 | |
| | | | $1.8V \pm 0.15V$ | 2.2 | 4.3 | 6.3 | 2.0 | 7.9 | 2.0 | 8.8 | |
| | | | $2.5V \pm 0.2V$ | 2.0 | 3.7 | 4.9 | 1.8 | 6.0 | 1.8 | 6.7 | |
| | | | $3.3V \pm 0.3V$ | 2.0 | 3.5 | 4.4 | 1.8 | 5.4 | 1.8 | 6.1 | |
| t_{en} | OE | Y | 0.8V | — | 79.2 | — | — | — | — | — | ns |
| | | | $1.2V \pm 0.1V$ | 3.6 | 7.8 | 15.8 | 3.3 | 17.1 | 3.3 | 17.1 | |
| | | | $1.5V \pm 0.1V$ | 3.0 | 5.4 | 8.8 | 2.9 | 9.4 | 2.9 | 9.7 | |
| | | | $1.8V \pm 0.15V$ | 2.1 | 4.3 | 6.7 | 2.0 | 7.3 | 2.0 | 7.7 | |
| | | | $2.5V \pm 0.2V$ | 1.8 | 3.4 | 4.8 | 1.7 | 5.2 | 1.7 | 5.6 | |
| | | | $3.3V \pm 0.3V$ | 1.6 | 3.1 | 4.3 | 1.5 | 4.5 | 1.5 | 4.7 | |
| t_{dis} | OE | Y | 0.8V | — | 14.9 | — | — | — | — | — | ns |
| | | | $1.2V \pm 0.1V$ | 3.7 | 9.0 | 12.7 | 3.7 | 13.0 | 3.7 | 13.0 | |
| | | | $1.5V \pm 0.1V$ | 2.5 | 8.1 | 11.5 | 2.5 | 12.0 | 2.5 | 12.0 | |
| | | | $1.8V \pm 0.15V$ | 2.0 | 7.9 | 10.1 | 2.0 | 10.4 | 2.0 | 10.4 | |
| | | | $2.5V \pm 0.2V$ | 1.7 | 7.7 | 9.7 | 1.7 | 9.9 | 1.7 | 9.9 | |
| | | | $3.3V \pm 0.3V$ | 1.5 | 7.2 | 9.0 | 1.5 | 9.3 | 1.5 | 9.3 | |

 $C_L = 30\text{pF}$, See Figure 1

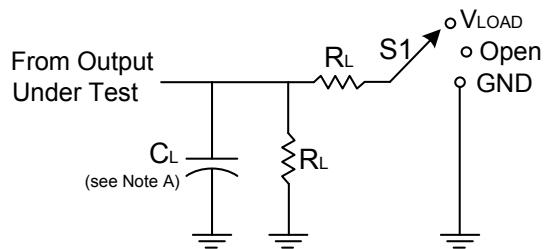
| Parameter | From Input | To Output | V_{CC} | $T_A = +25^\circ\text{C}$ | | | $T_A = -40^\circ\text{C} \text{ to } +85^\circ\text{C}$ | | $T_A = -40^\circ\text{C} \text{ to } +125^\circ\text{C}$ | | Unit |
|-----------|------------|-----------|------------------|---------------------------|------|------|---|------|--|------|------|
| | | | | Min | Typ | Max | Min | Max | Min | Max | |
| t_{pd} | A | Y | 0.8V | — | 37.4 | — | — | — | — | — | ns |
| | | | $1.2V \pm 0.1V$ | 4.8 | 9.5 | 18.7 | 4.4 | 21.4 | 4.4 | 24.0 | |
| | | | $1.5V \pm 0.1V$ | 4.0 | 6.7 | 10.8 | 3.0 | 13.0 | 3.0 | 14.5 | |
| | | | $1.8V \pm 0.15V$ | 2.5 | 5.6 | 8.4 | 2.5 | 10.3 | 2.5 | 11.5 | |
| | | | $2.5V \pm 0.2V$ | 2.2 | 4.8 | 6.3 | 2.2 | 7.8 | 2.2 | 8.7 | |
| | | | $3.3V \pm 0.3V$ | 2.0 | 4.6 | 5.8 | 2.0 | 7.0 | 2.0 | 8.3 | |
| t_{en} | OE | Y | 0.8V | — | 90.6 | — | — | — | — | — | ns |
| | | | $1.2V \pm 0.1V$ | 4.7 | 10.0 | 20.4 | 4.3 | 22.0 | 4.3 | 22.0 | |
| | | | $1.5V \pm 0.1V$ | 3.5 | 6.9 | 11.3 | 3.5 | 12.0 | 3.5 | 12.5 | |
| | | | $1.8V \pm 0.15V$ | 2.6 | 5.6 | 8.6 | 3.2 | 9.5 | 3.2 | 10.1 | |
| | | | $2.5V \pm 0.2V$ | 2.3 | 4.5 | 6.3 | 2.9 | 6.8 | 2.9 | 7.3 | |
| | | | $3.3V \pm 0.3V$ | 2.2 | 4.2 | 5.8 | 2.7 | 6.4 | 2.7 | 6.7 | |
| t_{dis} | OE | Y | 0.8V | — | 51.6 | — | — | — | — | — | ns |
| | | | $1.2V \pm 0.1V$ | 4.7 | 12.8 | 15.0 | 4.7 | 15.5 | 4.7 | 15.5 | |
| | | | $1.5V \pm 0.1V$ | 3.0 | 11.8 | 13.5 | 3.0 | 13.9 | 3.0 | 13.9 | |
| | | | $1.8V \pm 0.15V$ | 2.6 | 10.8 | 12.7 | 2.6 | 13.2 | 2.6 | 12.7 | |
| | | | $2.5V \pm 0.2V$ | 2.3 | 10.1 | 12.0 | 2.3 | 12.5 | 2.3 | 12.5 | |
| | | | $3.3V \pm 0.3V$ | 2.2 | 9.0 | 11.5 | 2.2 | 12.0 | 2.2 | 12.0 | |

Operating and Package Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Parameter | | Test Conditions | | V _{CC} | Typ | Unit |
|---------------|--|------------------------------|----------|-------------------------|-----|------|
| C_{pd} | Power Dissipation Capacitance | $f = 1\text{MHz}$ No Load | | 0.8V | 6.9 | pF |
| | | | | 1.2V $\pm 0.1\text{V}$ | 6.7 | |
| | | | | 1.5V $\pm 0.1\text{V}$ | 6.6 | |
| | | | | 1.8V $\pm 0.15\text{V}$ | 6.5 | |
| | | | | 2.5V $\pm 0.2\text{V}$ | 6.4 | |
| | | | | 3.3V $\pm 0.3\text{V}$ | 6.3 | |
| C_i | Input Capacitance | $V_i = V_{CC}$ or GND | | 0V or 3.3V | 1.5 | pF |
| θ_{JA} | Thermal Resistance Junction-to-Ambient | SOT353 | (Note 9) | — | 371 | °C/W |
| | | X2-DFN0808-4 | | — | 430 | |
| | | X1-DFN1010-6 | | — | 435 | |
| | | X2-DFN1010-6 | | — | 445 | |
| | | X2-DFN1409-6 | | — | 470 | |
| | | X2-DFN1410-6 | | — | 460 | |
| θ_{JC} | Thermal Resistance Junction-to-Case | SOT353 | (Note 9) | — | 143 | °C/W |
| | | X2-DFN0808-4 | | — | 240 | |
| | | X1-DFN1010-6 | | — | 250 | |
| | | X2-DFN1010-6 | | — | 250 | |
| | | X2-DFN1409-6 | | — | 275 | |
| | | X2-DFN1410-6 | | — | 265 | |

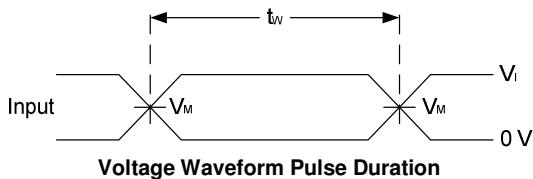
Note: 9. Test condition for each of the six package types: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Parameter Measurement Information

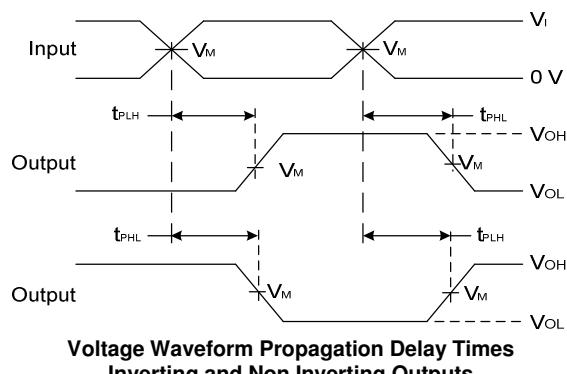


| TEST | S1 | R _L |
|------------------------------------|-------------------|----------------|
| t _{PLH} /t _{PHL} | Open | 1MΩ |
| t _{PLZ} /t _{PZL} | V _{load} | 5kΩ |
| t _{PHZ} /t _{PZH} | GND | 5kΩ |

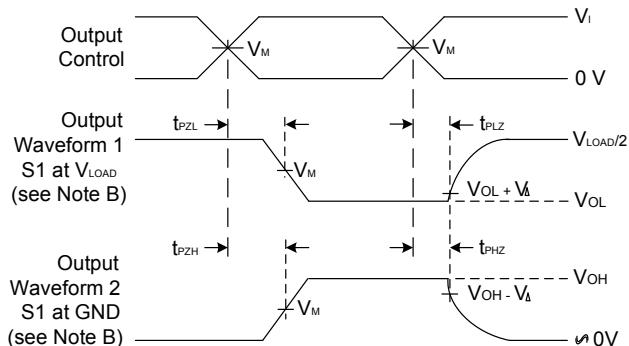
| V _{CC} | Inputs | | V _M | V _{LOAD} | C _L | V _Δ |
|-----------------|-----------------|--------------------------------|--------------------|---------------------|-----------------|----------------|
| | V _I | t _r /t _f | | | | |
| 0.8V | V _{CC} | ≤3ns | V _{CC} /2 | 2 X V _{CC} | 5, 10, 15, 30pF | 0.1V |
| 1.2V ± 0.1V | V _{CC} | ≤3ns | V _{CC} /2 | 2 X V _{CC} | 5, 10, 15, 30pF | 0.1V |
| 1.5V ± 0.1V | V _{CC} | ≤3ns | V _{CC} /2 | 2 X V _{CC} | 5, 10, 15, 30pF | 0.1V |
| 1.8V ± 0.15V | V _{CC} | ≤3ns | V _{CC} /2 | 2 X V _{CC} | 5, 10, 15, 30pF | 0.15V |
| 2.5V ± 0.2V | V _{CC} | ≤3ns | V _{CC} /2 | 2 X V _{CC} | 5, 10, 15, 30pF | 0.15V |
| 3.3V ± 0.3V | V _{CC} | ≤3ns | V _{CC} /2 | 2 X V _{CC} | 5, 10, 15, 30pF | 0.3V |



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times
Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times
Low and High Level Enabling

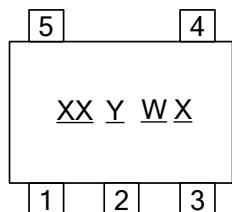
Figure 1 Load Circuit and Voltage Waveforms

- Notes:
- A. Includes test lead and test apparatus capacitance.
 - B. All pulses are supplied at pulse repetition rate $\leq 10\text{MHz}$.
 - C. Inputs are measured separately one transition per measurement.
 - D. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
 - E. t_{PZL} and t_{PZH} are the same as t_{EN}.
 - F. t_{PLH} and t_{PHL} are the same as t_{PD}.

Marking Information

(1) SOT353

(Top View)

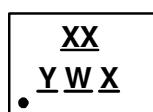


XX : Identification code
Y : Year 0~9
W : Week : A~Z : 1~26 week;
 a~z : 27~52 week; z represents
 52 and 53 week
X : A~Z : Internal code

| Part Number | Package | Identification Code |
|----------------|---------|---------------------|
| 74AUP1G126SE-7 | SOT353 | XZ |

(2) X2-DFN0808-4, X2-DFN1010-6 X2-DFN1409-6 and X2-DFN1410-6

(Top View)

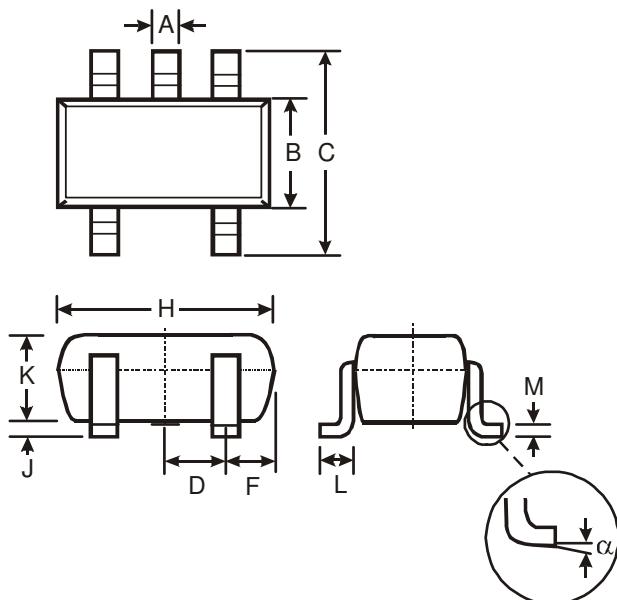


XX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
 a~z : 27~52 week; z represents
 52 and 53 week
X : A~Z : Internal code

| Part Number | Package | Identification Code |
|-----------------|--------------|---------------------|
| 74AUP1G126FS3-7 | X2-DFN0808-4 | YZ |
| 74AUP1G126FW5-7 | X1-DFN1010-6 | QY |
| 74AUP1G126FW4-7 | X2-DFN1010-6 | XZ |
| 74AUP1G126FX4-7 | X2-DFN1409-6 | HR |
| 74AUP1G126FZ4-7 | X2-DFN1410-6 | XZ |

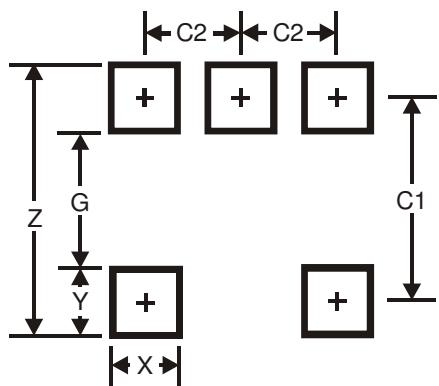
SOT353 Package Outline Dimensions and Suggested Pad Layout

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| SOT353 | | | |
|--------|------|------|-------|
| Dim | Min | Max | Typ |
| A | 0.10 | 0.30 | 0.25 |
| B | 1.15 | 1.35 | 1.30 |
| C | 2.00 | 2.20 | 2.10 |
| D | 0.65 | Typ | |
| F | 0.40 | 0.45 | 0.425 |
| H | 1.80 | 2.20 | 2.15 |
| J | 0 | 0.10 | 0.05 |
| K | 0.90 | 1.00 | 1.00 |
| L | 0.25 | 0.40 | 0.30 |
| M | 0.10 | 0.22 | 0.11 |
| α | 0° | 8° | - |

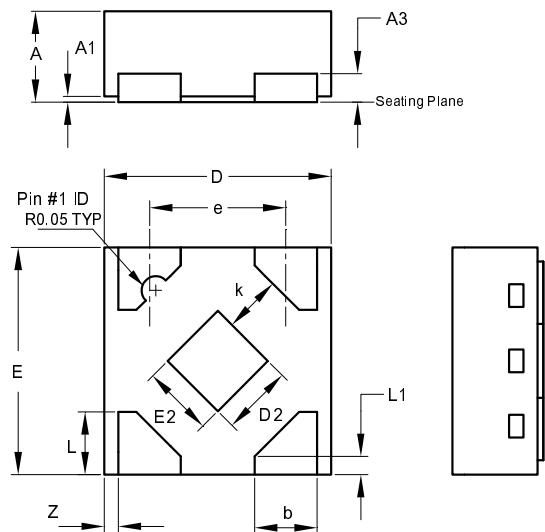
All Dimensions in mm



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.5 |
| G | 1.3 |
| X | 0.42 |
| Y | 0.6 |
| C1 | 1.9 |
| C2 | 0.65 |

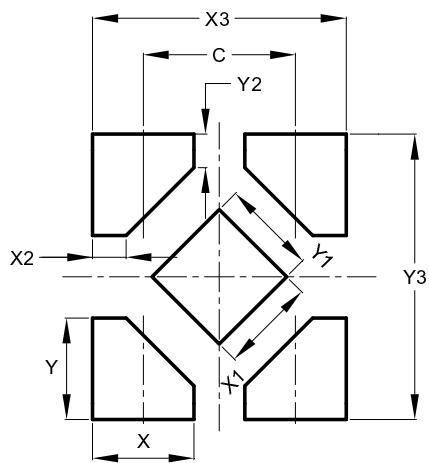
X2-DFN0808-4 Package Outline Dimensions and Suggested Pad Layout

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| X2-DFN0808-4 | | | |
|--------------|------|------|------|
| Dim | Min | Max | Typ |
| A | 0.25 | 0.35 | 0.30 |
| A1 | 0 | 0.04 | 0.02 |
| A3 | - | - | 0.13 |
| b | 0.17 | 0.27 | 0.22 |
| D | 0.75 | 0.85 | 0.80 |
| D2 | 0.15 | 0.35 | 0.25 |
| E | 0.75 | 0.85 | 0.80 |
| E2 | 0.15 | 0.35 | 0.25 |
| e | - | - | 0.48 |
| k | 0.20 | - | - |
| L | 0.17 | 0.27 | 0.22 |
| L1 | 0.02 | 0.12 | 0.07 |
| z | - | - | 0.05 |

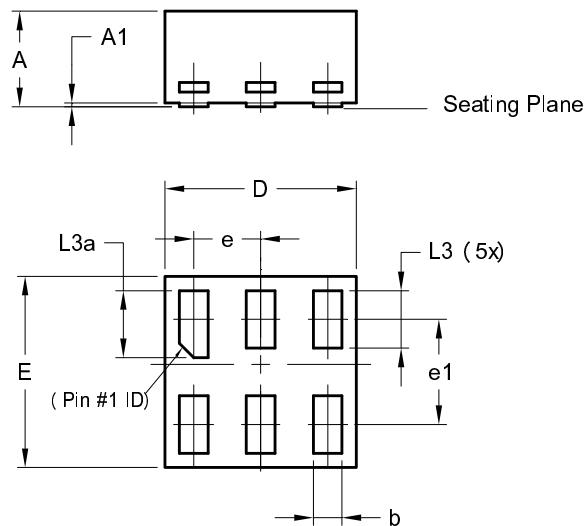
All Dimensions in mm



| Dimensions | Value |
|------------|-------|
| C | 0.480 |
| X | 0.320 |
| X1 | 0.300 |
| X2 | 0.106 |
| X3 | 0.800 |
| Y | 0.320 |
| Y1 | 0.300 |
| Y2 | 0.106 |
| Y3 | 0.900 |

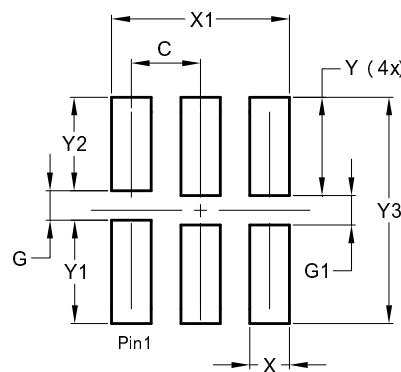
X1-DFN1010-6 (Type B) Package Outline Dimensions and Suggested Pad Layout

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| X1-DFN1010-6 (Type B) | | | |
|--------------------------|------|-------|------|
| Dim | Min | Max | Typ |
| A | - | 0.50 | 0.39 |
| A1 | - | 0.04 | - |
| b | 0.12 | 0.20 | 0.15 |
| D | 0.95 | 1.050 | 1.00 |
| E | 0.95 | 1.050 | 1.00 |
| e | 0.35 | BSC | |
| e1 | 0.55 | BSC | |
| L3 | 0.27 | 0.30 | 0.30 |
| L3a | 0.32 | 0.40 | 0.35 |

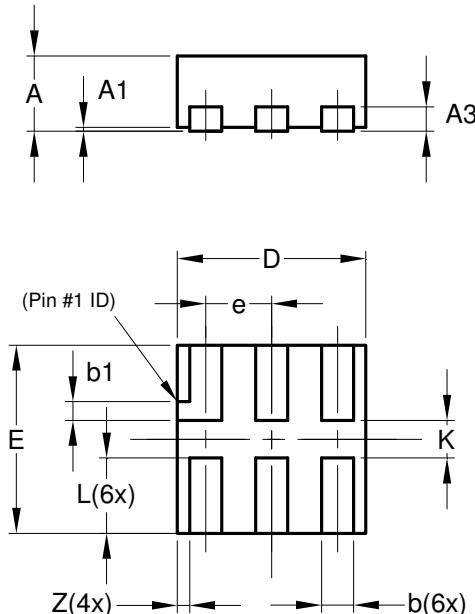
All Dimensions in mm



| Dimensions | Value (in mm) |
|------------|------------------|
| C | 0.350 |
| G | 0.150 |
| G1 | 0.150 |
| X | 0.200 |
| X1 | 0.900 |
| Y | 0.500 |
| Y1 | 0.525 |
| Y2 | 0.475 |
| Y3 | 1.150 |

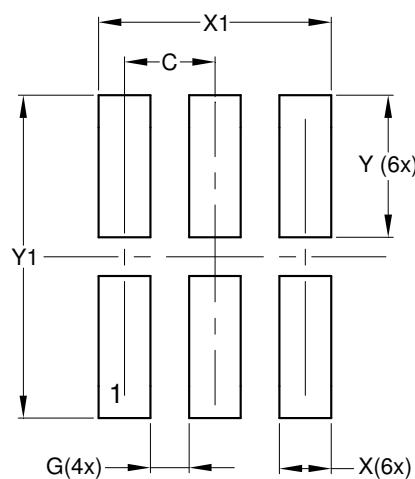
X2-DFN1010-6 Package Outline Dimensions and Suggested Pad Layout

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| X2-DFN1010-6 | | | |
|--------------|------|------|-------|
| Dim | Min | Max | Typ |
| A | — | 0.40 | 0.39 |
| A1 | 0.00 | 0.05 | 0.02 |
| A3 | — | — | 0.13 |
| b | 0.14 | 0.20 | 0.17 |
| b1 | 0.05 | 0.15 | 0.10 |
| D | 0.95 | 1.05 | 1.00 |
| E | 0.95 | 1.05 | 1.00 |
| e | — | — | 0.35 |
| L | 0.35 | 0.45 | 0.40 |
| K | 0.15 | — | — |
| Z | — | — | 0.065 |

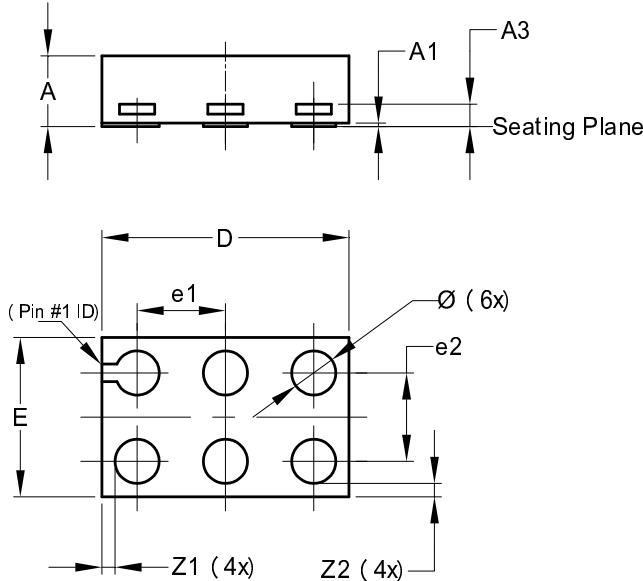
All Dimensions in mm



| Dimensions | Value (in mm) |
|------------|------------------|
| C | 0.350 |
| G | 0.150 |
| X | 0.200 |
| X1 | 0.900 |
| Y | 0.550 |
| Y1 | 1.250 |

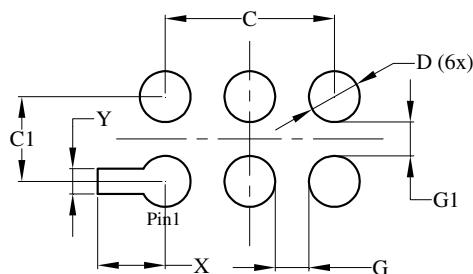
X2-DFN1409-6 Package Outline Dimensions and Suggested Pad Layout

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| X2-DFN1409-6 | | | |
|--------------|------|------|-------|
| Dim | Min | Max | Typ |
| A | - | 0.40 | 0.39 |
| A1 | 0 | 0.05 | 0.02 |
| A3 | - | - | 0.13 |
| Ø | 0.20 | 0.30 | 0.25 |
| D | 1.35 | 1.45 | 1.40 |
| E | 0.85 | 0.95 | 0.90 |
| e1 | - | - | 0.50 |
| e2 | - | - | 0.50 |
| Z1 | - | - | 0.075 |
| Z2 | - | - | 0.075 |

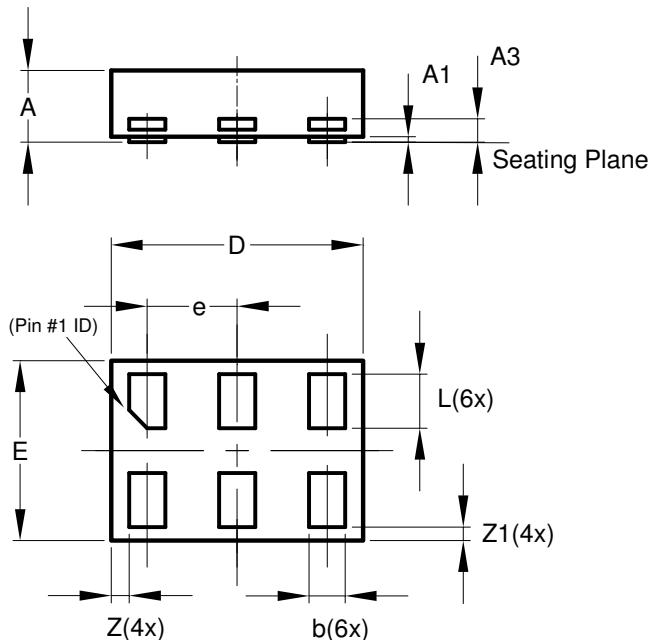
All Dimensions in mm



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 1.000 |
| C1 | 0.500 |
| D | 0.300 |
| G | 0.200 |
| G1 | 0.200 |
| X | 0.400 |
| Y | 0.150 |

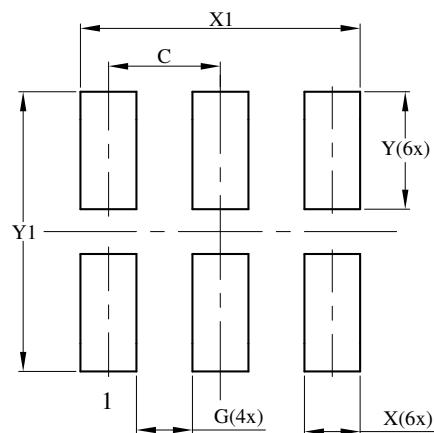
X2-DFN1410-6 Package Outline Dimensions and Suggested Pad Layout

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| X2-DFN1410-6 | | | |
|--------------|-------|-------|-------|
| Dim | Min | Max | Typ |
| A | — | 0.40 | 0.39 |
| A1 | 0.00 | 0.05 | 0.02 |
| A3 | — | — | 0.13 |
| b | 0.15 | 0.25 | 0.20 |
| D | 1.35 | 1.45 | 1.40 |
| E | 0.95 | 1.05 | 1.00 |
| e | — | — | 0.50 |
| L | 0.25 | 0.35 | 0.30 |
| Z | — | — | 0.10 |
| Z1 | 0.045 | 0.105 | 0.075 |

All Dimensions in mm



| Dimensions | Value (in mm) |
|------------|------------------|
| C | 0.500 |
| G | 0.250 |
| X | 0.250 |
| X1 | 1.250 |
| Y | 0.525 |
| Y1 | 1.250 |

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- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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